

RD5CYDT08

IGBT Driver / CMOS Logic Level Shifter

REJ03D0181-0700 Rev.7.00 Apr 22, 2008

Description

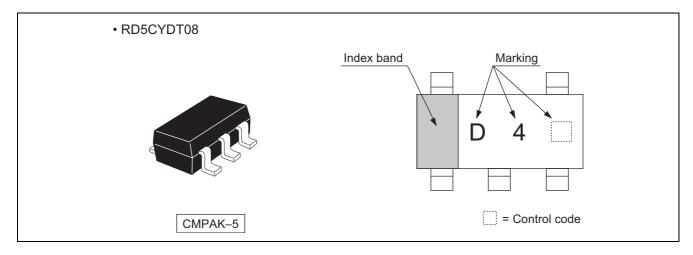
The RD5CYDT08 has two-input AND gate in a 5 pin package. This product is suited as IGBT Driver IC for the strobe.

Features

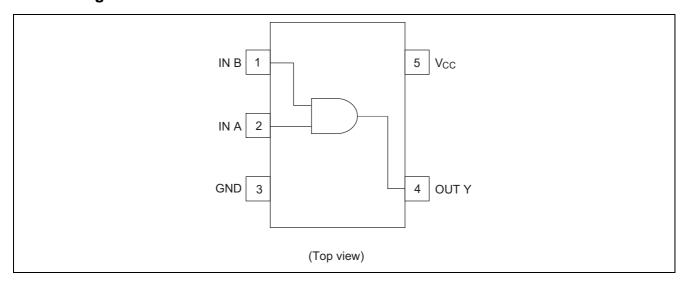
- Supplied on emboss taping for high-speed automatic mounting.
- TTL compatible input level
- Supply voltage range: 4.0 to 6.0 V
- Operating temperature range: -40 to +85°C
- Logic-level translate function 3.0 V CMOS logic → 5.0 V CMOS logic
- High drive current I_{OH} short = -130 mA (min) (@V_{CC} = 5.0 V)
- Low sink current I_{OL} short = 40 mA (max) (@V_{CC} = 5.0 V)
- Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)
RD5CYDT08CME	CMPAK-5 pin	PTSP0005ZC-A (CMPAK-5V)	СМ	E (3,000 pcs/reel)

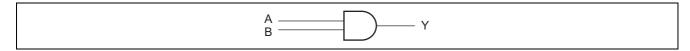
Outline and Article Indication



Pin Arrangement



Logic Diagram



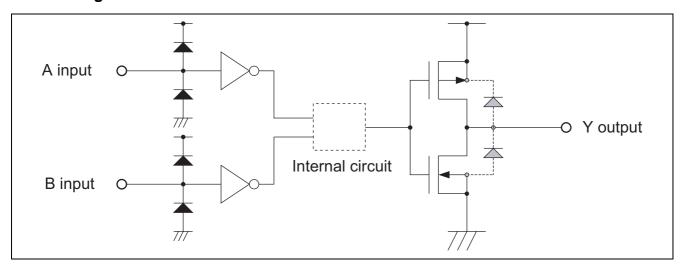
Function Table

Inp	Output Y	
Α	В	Output 1
L	L	L
Н	L	L
L	Н	L
Н	Н	Н

H: High level

L: Low level

Block Diagram



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Test Conditions
Supply voltage range	Vcc	-0.5 to 7.0	V	
Input voltage range *1	Vı	-0.5 to V _{CC} + 0.5	V	
Output voltage range *1, 2	Vo	-0.5 to V _{CC} + 0.5	V	
Input clamp current	I _{IK}	±20	mA	$V_I < 0$ or $V_I > V_{CC}$
Output clamp current	I _{OK}	±50	mA	$V_O < 0$ or $V_O > V_{CC}$
Continuous output current	lo	-200	mA	$V_O = 0$
		100	IIIA	$V_O = V_{CC}$
Continuous current through V _{CC} or GND	I _{CC} or I _{GND}	±200	mA	
Maximum power dissipation at Ta = 25°C (in still air) *3	P _T	200	mW	
Storage temperature	Tstg	-65 to 150	°C	

Notes: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore no two of which may be realized at the same time.

- 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed. When Over shoot / Under shoot pulse width is under 10 ns, input and output voltage permit to -15 V or V_{CC}+1.5 V.
- 2. This value is limited to 5.5 V maximum.
- 3. The maximum package power dissipation was calculated using a junction temperature of 150°C.

Recommended Operating Conditions

Item	Symbol	Min	Max	Unit	Conditions
Supply voltage range	V_{CC}	4.0	6.0	V	
Input voltage range	Vı	0	V _{CC}	V	
Output voltage range	Vo	0	V _{CC}	V	
Operating free-air temperature	Ta	-40	85	°C	

Note: Unused or floating inputs must be held high or low.

Electrical Characteristic

 $Ta = -40 \text{ to } 85^{\circ}C$

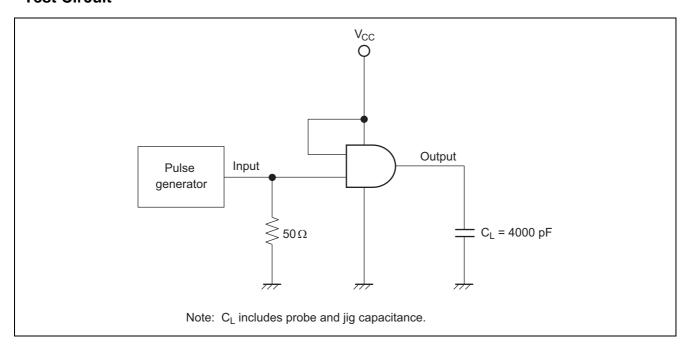
							1a = -40 to 65 C
Item	Symbol	V _{CC} (V)	Min	Тур	Max	Unit	Test condition
Input voltage	V_{IH}	4.5 to 5.5	2.0	_	_	V	
Input voltage	V _{IL}	4.5 to 5.5	_	_	0.8]	
Output ourropt	I _{OH} short	5.0	-100	-130	-160	ı mΔ -	$V_O = 0 V$
Output current	I _{OL} short	5.0	30	40	50		$V_O = V_{CC}$
Input current	I _{IN}	5.5	_	_	±5	μΑ	$V_{IN} = 5.5 \text{ V or GND}$
Quiescent supply current	I _{CC}	5.5	_	_	10	μΑ	$V_{IN} = V_{CC}$ or GND, $I_O = 0$
Input capacitance	C _{IN}	5.0	_	2.5	_	pF	$V_{IN} = V_{CC}$ or GND

Switching Characteristics

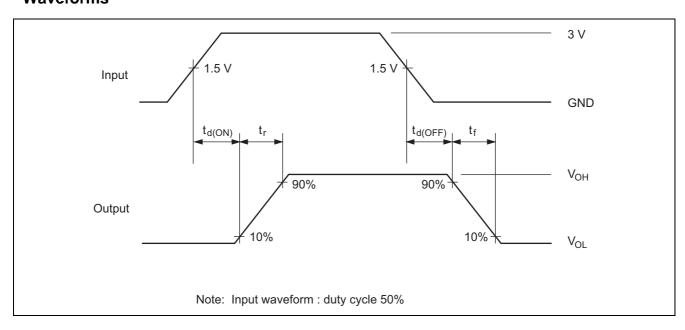
 $V_{CC}=5.0\pm0.5\ V$

Item	Symbol Ta = -40 to 85°C		5°C	Unit	Test	FROM	ТО	
	Symbol	Min	Тур	Max	Ollic	Conditions	(Input)	(Output)
Propagation delay time	t _{d(ON)}	_	_	70				
Fropagation delay time	t _{d(OFF)}	_	_	140	ne	$C_1 = 4000 \text{ pF}$	A or B	V
Output rise time	t _r	_	_	800	ns	115 C _L = 4000 pr	AUID	'
Output fall time	t _f	_	_	1500				

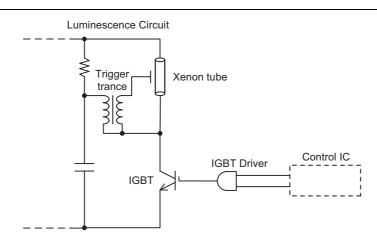
Test Circuit



Waveforms



Application Example (Strobe circuit)



Combination example

SYSTEM	IGBT	IGBT Driver	Control IC
3.3 V	RJP4002ANS RJP4002ASA	RD3CYD08 RD3CYDT08	3.3 V signal
5.0 V	RJP4003ANS RJP4003ASA	RD5CYD08 RD5CYDT08	

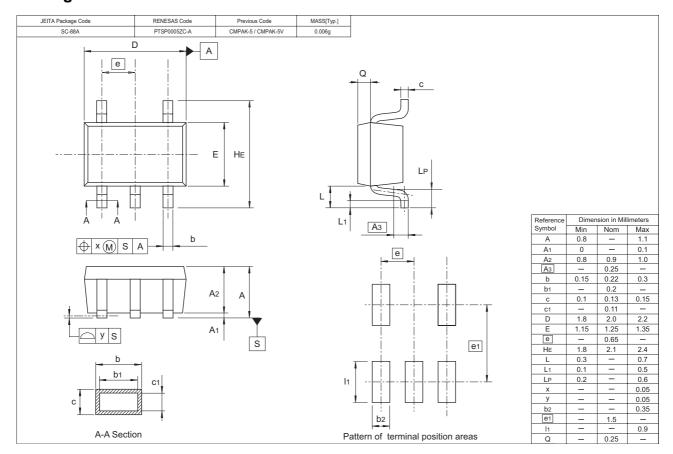
IGBT Driver Lineup

TYPE No.	Specification	Package	
RD3CYD08	V_{CC} = 2.0 to 3.6V CMOS lever input $I_{OH}(short)$ = -130mA(typ) @ V_{CC} = 3.3V $I_{OL}(short)$ = 45mA(typ) @ V_{CC} = 3.3V	CMPAK-5 VSON-5	
RD3CYDT08	V_{CC} = 2.0 to 3.6V CMOS lever input $I_{OH}(short)$ = -130mA(typ) @ V_{CC} = 3.3V $I_{OL}(short)$ = 45mA(typ) @ V_{CC} = 3.3V	CMPAK-5	
RD5CYD08	V_{CC} = 4.0 to 6.0V CMOS lever input $I_{OH}(short)$ = -130mA(typ) @ V_{CC} = 5.0V $I_{OL}(short)$ = 40mA(typ) @ V_{CC} = 5.0V	CMPAK-5	
RD5CYDT08	V_{CC} = 4.0 to 6.0V TTL lever input $I_{OH}(short)$ = -130mA(typ) @ V_{CC} = 5.0V $I_{OL}(short)$ = 40mA(typ) @ V_{CC} = 5.0V	CMPAK-5	

IGBT Lineup

TYPE No.	Specification	Package
RJP4002ANS	V _{CES} = 400V(max), I _{CP} = 150A(max), 2.5V drive	VSON-8
RJP4002ASA	V _{CES} = 400V(max), I _{CP} = 150A(max), 2.5V drive	TSSOP-8
RJP4003ANS	V _{CES} = 400V(max), I _{CP} = 150A(max), 4V drive	VSON-8
RJP4003ASA	V _{CES} = 400V(max), I _{CP} = 150A(max), 4V drive	TSSOP-8

Package Dimensions



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